

SANYO Semiconductors DATA SHEET

LA72702VA — For US TV BTSC Decoder

Overview

The LA72702VA is a US TV BTSC Decoder.

Features

- With SIF circuit, alignment-free* STEREO channel separation.
- * When Base Band signal input, separation is adjusted by input level.
- Dual Slave address.

Functions

- IF FM-Demodulator.
- STEREO decoder.
- dbx Noise Reduction.
- STEREO detection.
- STEREO detection sensitivity change function.
- SAP demodulator.
- SAP detection.
- SAP output select 2-levels.
- SAP detection sensitivity change function.

Specifications

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum power supply voltage	V _{CC} max		7.0	V
Allowable power dissipation	Pd max	Ta ≤ 70°C *	290	mW
Operating temperature	Topr		-10 to +70	°C
Storage temperature	Tstg		-55 to +150	°C

^{*} When mounted on a 114.3mm×76.1mm×1.6mm glass epoxy board.

- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment (home appliances, AV equipment, communication device, office equipment, industrial equipment etc.). The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for applications outside the standard applications of our customer who is considering such use and/or outside the scope of our intended standard applications, please consult with us prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

Operating Ranges at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended operating voltage	VCC		5.0	V
Allowable operating voltage range	V _{CC} op		4.5 to 5.5	V

Caution: Please use this IC under license contract with THAT Corporation, because this IC is included dbx noise reduction system.

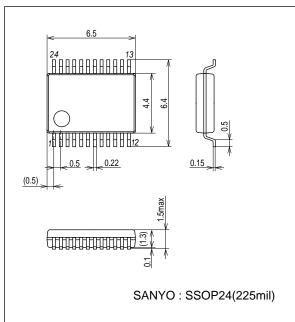
Electrical Characteristics at Ta = 25°C, $V_{DD} = 5.0V$

Parameter	Symbol	Conditions		Ratings		Unit
r drameter	Cymbol	Conditions	min	typ	max	OTIN
Current dissipation	lcc	No signal Inflow current at pin 19, default condition	30	40	50	mA
SIF input level (Reference)	V _I LIM	fc = 4.5MHz Deviation MONO (300Hz, Mod = 100%, Pre-emphasis ON) → ±25kHz	(80)	(90)	(100)	dΒμV
Base band input level (Reference)	V _I LIMB	100% Modulation MONO(L+R) : 530mVp-p (300Hz, Pre-emphasis ON SUB(L-R) : 380mVp-p (300Hz, dbx-NR ON), Pilot SAP : 300mVp-p (300Hz, dbx-NR ON)	•	o		
MONO output level	V _O MON	fm = 1kHz, 100% Mod, 15kHz LPF	-6.5	-5.5	-4.5	dBV
MONO distortion	THDMON	fm = 1kHz, 100% Mod, 15kHz LPF		0.15	0.6	%
MONO frequency characteristics	FCM1	fm = 3kHz, 30% Mod, Ore-em. ON * Measure ratio from fm = 1kHz level.	-2	0	2	dB
MONO S/N ratio	SNM	S = V _O MON, N = 0% Mod, 15kHz LPF	55	65		dB
STEREO output level	V _O ST	fm = 1kHz, 100% Mod, 15kHz LPF	-7.0	-5.5	-3.0	dBV
STEREO distortion	THDS	fm = 1kHz, 100% Mod, 15kHz LPF		1.0	2.5	%
STEREO frequency characteristics	FCS1	fm = 3kHz, 30% Mod, 15kHz LPF * Measure ratio from fm = 1kHz level.	-3	0	3	dB
STEREO S/N ratio	SNS	S = V _O ST, N = 0% Mod, 15kHz LPF	50	60		dB
STEREO separation 1	STSE1	f = 300Hz (R/L), 30% Mod, 15kHz LPF	15	25		dB
STEREO separation 2	STSE2	f = 3kHz (R/L), 30% Mod, 15kHz LPF	15	25		dB
STEREO Detection level-1	V _{IN} SD1	Except Stereo Detection → Stereo Detection * serial control 1 "SENS HI" Pilot (fH) = 15.73kHz * Measure Pilot level.	30	35	40	%
STEREO Detection level-2	V _{IN} SD2	Except Stereo Detection → Stereo Detection * serial control "SENS LO"	40	45	50	%
STEREO Detection hysteresis	HYST	Input Mod. Difference at Stereo/Except Stereo Det. * serial control 1 "SENS HI"	10	20	30	%
SAP output level-1	V _O SA1	fm = 1kHz, 100% Mod, 15kHz LPF * SAP-1 (serial control)	-14.0	-11.0	-8.0	dBV
SAP output level-2	V _O SA2	fm = 1kHz, 100% Mod, 15kHz LPF * SAP-2 (serial control)	-12.0	-9.0	-6.0	dBV
SAP distortion	THDSA	fm = 1kHz, 100% Mod, 15kHz LPF		2.5	3.5	%
SAP S/N ratio	SNSA	S = V _O SA, N = 0% Mod, 15kHz LPF	50	60		dB
SAP detection level-1	V _{IN} SA1	Except SAP → SAP Det. * serial control 1 "SENS HI" SAP Carrier = 5fH only * Measure Output level.	10	15	20	%
SAP detection level-2 (Reference)	V _{IN} SA2	Except SAP → SAP Det. * serial control 1 "SENS LO" * Measure Output level.	15	20	25	%
* SAP carrier only.		Input Mod. Difference at SAP/Except SAP Det. * SAP carrier only. * serial control 1 "SENS HI"	2	5	10	%
MODE output MONO	MODMO	Input = MONO : f = 1kHz, 0% Mod	0.7	1	1.3	V
MODE output SAP	MODSA	Input = SAP : Carrier	1.6	1.9	2.2	V
MODE output STEREO	MODST	Input = STEREO : Pilot	2.5	2.8	3.1	V
MODE output ST + SAP	3.5	3.8	4.2	V		

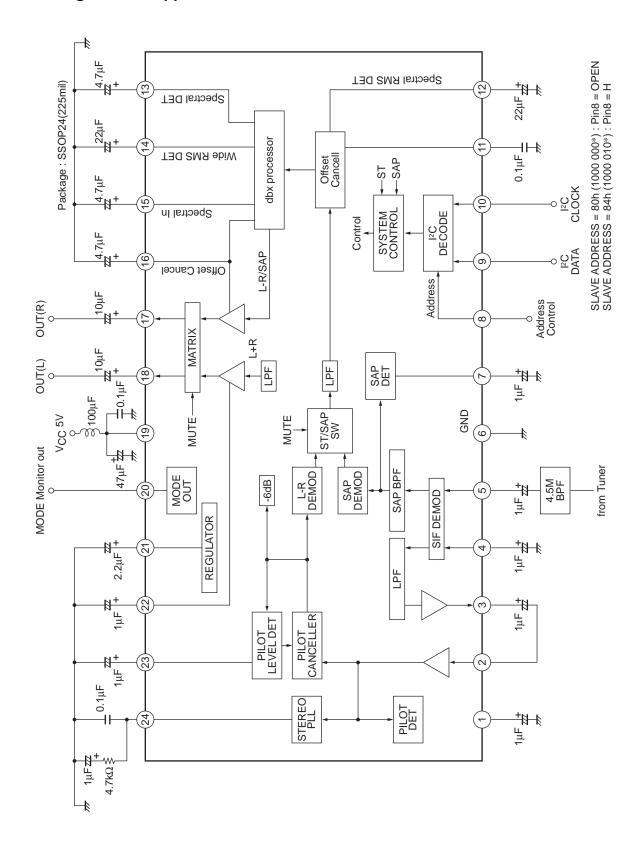
^{*} Normally measurement condition is Input = SIF mode ($90dB\mu V$)

 $^{^{\}star}$ " Reference " Items are reference levels, their specs are no-guarantee.

Package Dimensions unit: mm (typ) 3287



Block Diagram and Application



Pin Functions

Pin No.	Pin Name	Function	DC voltage	Equivalent Circuit
			AC level	Equivalent Circuit
1	PCPLDET	Pilot level detect For Stero Detection	DC: 2.4V	40kΩ 1 1kΩ 1 160kΩ
2	PC DC IN	AC coupling (Input)	DC: 2.4V AC: 2.4Vp-p	3 2
3	PC DCOUT	AC coupling (Output)	DC: 2.4V AC: 2.4Vp-p	500Ω 3 2 1κΩ
4	PISIF	Signal input Common input at SIF, Baseband	DC: 3.7V	5kΩ 4 500Ω 1kΩ
5	PC FIL	SIF offset cancel	DC: 2.6V	1kΩ 1kΩ 5
6	GND			
7	CSAPDET	SAP carrier level detect For SAP detection	DC: 2.8V	$\begin{array}{c c} & & & & \\ & & & & \\ & & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ &$
8	ADDSEL	Slave Address change control OPEN/GND: 80h 5V: 84h	DC:0V	8 *100kΩ

Continued on next page

Continued	from preceding page.		1	
Pin No.	Pin Name	Function	DC voltage AC level	Equivalent Circuit
9	SDA	Serial data input	5V 0V	9 1κΩ
10	SCL	Serial clock input	5V 0V	10
11	PC DBXIN	Offset cancel Feedback filter	DC : 1.6V	450kΩ 110 500Ω
12	PCDETSPE	Spectral band RMS detect	DC : 2.3V	1kΩ 200Ω
13	PCTIMSPE	dbx spectral detect	DC: 2.4V	13 - 5kΩ + 1
14	PCTNWID	dbx RMS detect (wide band)	DC: 2.4V	1kΩ 2200Ω
15	PCSPECIN	dbx main signal V/I convert filter	DC : 2.4V	10kΩ 15
16	PC KE6B	Offset cancel filter	DC : 2.4V AC : 220mVp-p	$\begin{array}{c} 250\Omega \\ \hline \\ 500\Omega \\ \end{array}$ Continued on next page

Continued on next page

Continued	from preceding page.	,		,
Pin No.	Pin Name	Function	DC voltage AC level	Equivalent Circuit
17	PORCH	Line out R	DC : 2.4V AC : 1.4Vp-p	\$50kΩ \$300Ω \$50kΩ \$50kΩ
18	POLCH	Line out L	DC : 2.4V AC : 1.4Vp-p	\$50kΩ \$50kΩ \$300Ω \$50kΩ \$50kΩ
19	V _{CC}			
20	POLED	MONO = 3.0V SAP = 2.0V STEREO = 1.0V STEREO + SAP = 3.8V Mode out	DC : See Right AC Test only	20 1κΩ
21	PCREG	Reference Voltage	DC : 2.4V	10kΩ \$9.6kΩ \$1kΩ (21)
23	PCPLC	Pilot level detect For Pilot canceller	DC: 2.4V	40kΩ 1kΩ 160kΩ 23
24	PCPLDET	Pilot level detect For ST PLL filter	DC : 2.4V	40kΩ 40kΩ 1kΩ 160kΩ

I²C BUS serial interface specification

(1) Data Transfer Manual

This IC adopts control method(I²C-BUS) with serial data, and controlled by two terminals which called SCL(serial clock) and SDA (serial data). At first, set up*1 the condition of starting data transfer, and after that, input 8 bit data to SDA terminal with synchronized SCL terminal clock. The order of transferring is first, MSB (the Most Scale of Bit), and save the order. The 9th bit takes ACK (Acknowledge) period, during SCL terminal takes 'H', this IC pull down the SDA terminal. After transferred the necessary data, two terminals lead to set up and of *2 data transfer stop condition, thus the transfer comes to close.

- *1 Defined by SCL rise down SDA during 'H' period.
- *2 Defined by SCL rise up SDA during 'H' period.

(2) Transfer Data Format

After transfer start condition, transfers slave address (1000 000*) to SDA terminal, control data, then, stop condition (See figure 1).

Slave address is made up of 7bits, 8th bit^{*3} shows the direction of transferring data, if it is 'L' takes write mode (As this IC side, this is input operation mode), and in case of 'H' reading mode (As this IC side, this is output operation mode). Data works with all of bit, transfer the stop condition before stop 8bit transfer, and to stop transfer, it will be canceled the transfer dates.

*3 It is called R/W bit.

Fig.1 DATA STRUCTURE "WRITE" mode

START Condition Slave Address R/WL ACK	Control data ACK	STOP condition
--	------------------	----------------

Fig.2 DATA STRUCTURE "READ" mode

		1 1			
START condition	Slave Address	R/W <u>H</u> ACK	Internal Data *	ACK	STOP condition

^{*} Output data as follows;

bit8 is result of STERO DET (H: STEREO), bit7 is result of SAP DET (H: SAP), bit6 to bit1 are fixed to 'L'

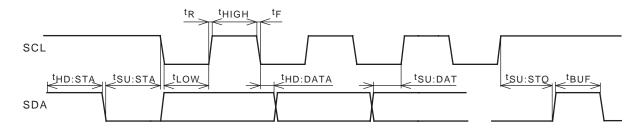
(3) Initialize

This IC is initialized for circuit protection. Initial condition is "0 (All bits)".

I²C Timing Specifications

Parameter	Symbol	min	max	unit
LOW level input voltage	V _{IL}	-0.5	1.5	V
HIGH level input voltage	V _{IH}	3.0	5.5	V
LOW level output current	loL		3.0	mA
SCL clock frequency	fSCL	0	100	kHz
Set-up time for a repeated START condition	^t SU : STA	4.7		μs
Hold time START condition. After this period, the first clock pulse is generated	tHD : STA	4.0		μs
LOW period of the SCL clock	tLOW	4.7		μs
Rise time of both SDA and SDL signals	t _R	0	1.0	μs
HIGH period of the SCL clock	tHIGH	4.0		μs
Fall time of both SDA and SDL signals	tF	0	1.0	μs
Data hold time :	tHD : DAT	0		μs
Data set-up time	^t SU : DAT	250		ns
Set-up time for STOP condition	tsu : sto	4.0		μs
BUS free time between a STOP and START condition	^t BUF	4.7		μs

Definition of timing



I²C Control Table

Grp-1 (Normally use : group-1 only)

	٠,٢	1 (140		400 .	9.04		,		
	D8	D7	D6	D5	D4	D3	D2	D1	Condition
*							0	0	Stereo
							0	1	SAP
							1	0	Both
							1	1	MUTE
*						0			Normal (Auto det)
						1			Forced Mono
*					0				SAP SENS LO
					1				SAP SENS HI
*				0					Stereo SENS LO
				1					Stereo SENS HI
*			0						SAP Level-1
			1						SAP Level-2
*		0							SIF mode
		1							Base Band mode
*	0								Fix
	1								Prohibit (TEST MODE)

^{*:} Shows Initial condition

Read out data

D8	D7	D6	D5	D4	D3	D2	D1	Condition
		0	0	0	0	0	0	Fixed
	0							Normal
	1							SAP det
0								Normal
1								Stereo det

Test mode condition

When STOP condition transform at Grp-1 data-end, controlled NORMAL mode. Grp-2 (Only test condition : Normally, this data is no-need)

D8	D7	D6	D5	D4	D3	D2	D1	Condition/Monitor position
0	0	0	0	0	0	0	0	Normal (Usually, Fixed)
0	0	0	0	0	0	0	1	TEST-1 SIF output
0	0	0	0	0	0	1	0	TEST-2 SAP BPF
0	0	0	0	0	0	1	1	TEST-3 (reserved)
0	0	0	0	0	1	0	0	TEST-4 ST VCO
0	0	0	0	0	1	0	1	TEST-5 (reserved)
0	0	0	0	0	1	1	0	TEST-6 SAP monitor
0	0	0	0	0	1	1	1	TEST-7 ST monitor
0	0	0	0	1	0	0	0	TEST-8 Pilot cancel monitor
0	0	0	0	1	0	0	1	TEST-9 dbx 2.19k LPF
0	0	0	0	1	0	1	0	TEST-10 dbx 408 LPF
0	0	0	0	1	0	1	1	TEST-11 dbx DET 10k LPF
0	0	0	0	1	1	0	0	TEST-12 dbx SPEC 7.6k LPF
0	0	0	0	1	1	0	1	TEST-13 dbx SPEC output
0	0	0	0	1	1	1	0	TEST-14 (reserved)
0	0	0	0	1	1	1	1	TEST-15 dbx 2.09k LPF

Blanc Bit are no-care

Mode Condition

	Detection		control				output		
SIGNAL	ST	SAP	System	Mute	Mono	Mode Condition	18 L ch	17 R ch	20 Mode
STEREO + SAP	ST DET	SAP DET	STEREO	L : NORM	L : NORM	STEREO	L	R	3.8V
			вотн	L : NORM	L : NORM	MULTI	LR	SAP	
			SAP	L : NORM	L : NORM	SAP	SAP	SAP	
			STEREO	L : NORM	H : MONO	MONO	L+R	L+R	
			вотн	L : NORM	H : MONO	MONO	L+R	L+R	
			SAP	L : NORM	H : MONO	MONO	L+R	L+R	
STEREO	ST DET		STEREO	L : NORM	L : NORM	STEREO	L	R	3.0V
			вотн	L : NORM	L : NORM	STEREO	L	R	
			SAP	L : NORM	L : NORM	STEREO	L	R	
			STEREO	L : NORM	H : MONO	MONO	L+R	L+R	
			вотн	L : NORM	H : MONO	MONO	L+R	L+R	
			SAP	L : NORM	H : MONO	MONO	L+R	L+R	
MONO + SAP		SAP DET	STEREO	L : NORM	L : NORM	MONO	L+R	L+R	2.0V
			вотн	L : NORM	L : NORM	MULTI	L+R	SAP	
			SAP	L : NORM	L : NORM	SAP	SAP	SAP	
			STEREO	L : NORM	H : MONO	MONO	L+R	L+R	
			вотн	L : NORM	H : MONO	MONO	L+R	L+R	
			SAP	L : NORM	H : MONO	MONO	L+R	L+R	
MONO			STEREO	L : NORM	L : NORM	MONO	L+R	L+R	1.0V
			вотн	L : NORM	L : NORM	MONO	L+R	L+R	
			SAP	L : NORM	L : NORM	MONO	L+R	L+R	
			STEREO	L : NORM	H : MONO	MONO	L+R	L+R]
			вотн	L : NORM	H : MONO	MONO	L+R	L+R	
			SAP	L : NORM	H : MONO	MONO	L+R	L+R	
*	*	*	*	H : MUTE	*	MUTE	OFF	OFF	Each

^{*:} no problem

- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of February, 2007. Specifications and information herein are subject to change without notice.